

#### 20V N-Channel Enhancement Mode MOSFET

Voltage 20 V Current 750mA

#### **Features**

- Low Voltage Drive (1.2V).
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc.
- ESD Protected
- Lead free in compliance with EU RoHS 2011/65/EU directive..
- Green molding compound as per IEC61249 Std. (Halogen Free)

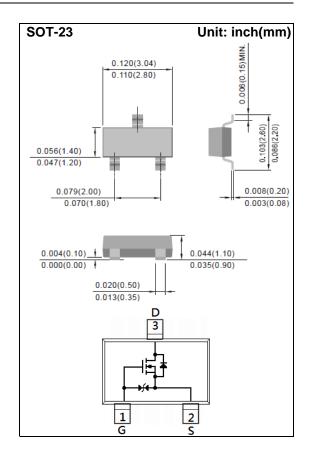
#### **Mechanical Data**

• Case: SOT-23 Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams

Marking: A34



## $\textbf{Maximum Ratings and Thermal Characteristics} \; (T_A \! = \! 25^{\circ} \text{C unless otherwise noted})$

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V <sub>DS</sub>	20	V
Gate-Source Voltage		V <sub>GS</sub>	<u>+</u> 10	V
Continuous Drain Current		I <sub>D</sub>	750	mA
Pulsed Drain Current (Note 4)		I <sub>DM</sub>	1500	mA
Power Dissipation	T <sub>a</sub> =25°C	_	500	mW
	Derate above 25°C	P₀	4	mW/°C
Operating Junction and Storage Temperature Range		TJ,TSTG	-55~150	°C
Typical Thermal resistance				
- Junction to Ambient (Note 3)		R <sub>θJA</sub>	250	°C/W



### **Electrical Characteristics** (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =250uA	20	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =250uA	0.3	0.65	1.0	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =4.5V, I <sub>D</sub> =600mA	-	280	400	mΩ	
		V <sub>GS</sub> =2.5V, I <sub>D</sub> =200mA	-	350	650		
		V <sub>GS</sub> =1.8V, I <sub>D</sub> =100mA	-	400	800		
		V <sub>GS</sub> =1.5V, I <sub>D</sub> =50mA	-	500	1200		
		V <sub>GS</sub> =1.2V, I <sub>D</sub> =20mA	-	1000	3000		
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =16V, V <sub>GS</sub> =0V	-	0.01	1	uA	
Gate-Source Leakage Current	Igss	V <sub>GS</sub> = <u>+</u> 8V, V <sub>DS</sub> =0V	-	<u>+</u> 0.5	<u>+</u> 10	uA	
Dynamic (Note 5)							
Total Gate Charge	$Q_g$	\/ 40\/   000mA	-	1.4	-	nC	
Gate-Source Charge	$Q_gs$	V <sub>DS</sub> =10V, I <sub>D</sub> =600mA,	-	0.22	-		
Gate-Drain Charge	$Q_gd$	VGS=4.5 V (***********************************	-	0.21	-		
Input Capacitance	Ciss	V <sub>DS</sub> =10V, V <sub>GS</sub> =0V,	-	67	-		
Output Capacitance	Coss	f=1.0MHZ	-	19	-	pF	
Reverse Transfer Capacitance	Crss	I=1.0IVII1Z	-	6	-		
Turn-On Delay Time	td <sub>(on)</sub>	\/ 10\/ I- 150mA	-	2.8	-		
Turn-On Rise Time	tr	V <sub>DD</sub> =10V, I <sub>D</sub> =150mA, V <sub>GS</sub> =4.0V,		20	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>	VGS=4.0V, R <sub>G</sub> =10Ω (Note 1,2)		23	-		
Turn-Off Fall Time	tf	NG=1002 (*******)=/	-	23	-		
Drain-Source Diode							
Maximum Continuous Drain-Source Diode Forward Current	ls		-	-	0.5	А	
Diode Forward Voltage	$V_{\text{SD}}$	Is=0.5A, V <sub>G</sub> s=0V		0.87	1.3	V	

#### NOTES:

- 1. Pulse width<300us, Duty cycle<2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.



#### **TYPICAL CHARACTERISTIC CURVES**

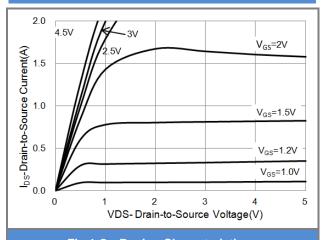
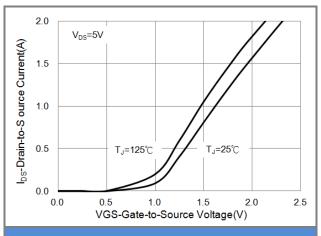


Fig.1 On-Region Characteristics



**Fig.2 Transfer Characteristics** 

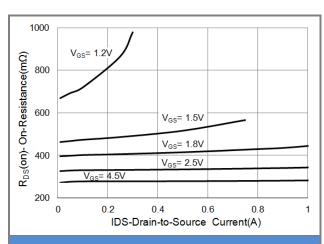


Fig.3 On-Resistance vs. Drain Current

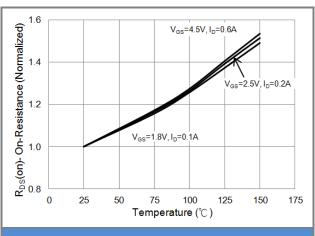


Fig.4 On-Resistance vs. Junction temperature

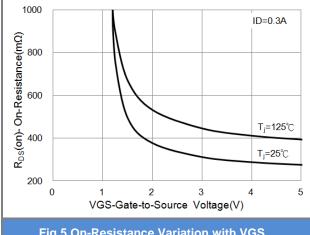
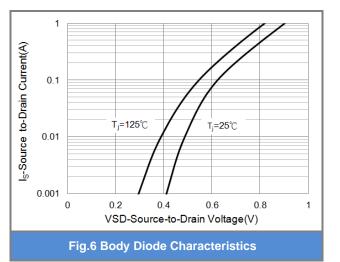


Fig.5 On-Resistance Variation with VGS.





#### **TYPICAL CHARACTERISTIC CURVES**

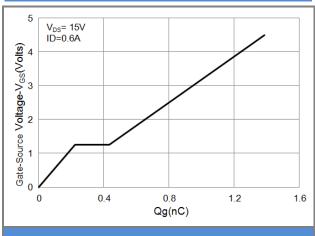


Fig.7 Gate-Charge Characteristics

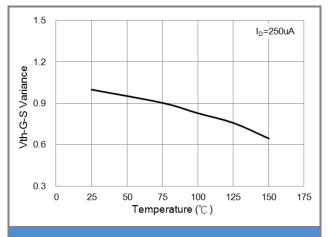


Fig.8 Threshold Voltage Variation with Temperature.

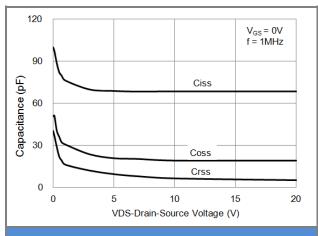


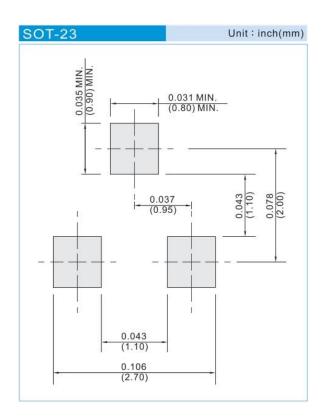
Fig.9 Capacitance vs. Drain-Source Voltage.



## **Product and Packing Information**

Part No.	Package Type	Packing Type	Marking	
PJA3434	SOT-23	3K pcs / 7" reel	A34	
PJA3434	SOT-23	12K pcs / 13" reel	A34	

## **Mounting Pad Layout**





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